

MEG実験用液体X γ 線検出器用 光電子増倍管についてI

東京大学素粒子物理国際研究センター

森研究室修士2年
久松康子

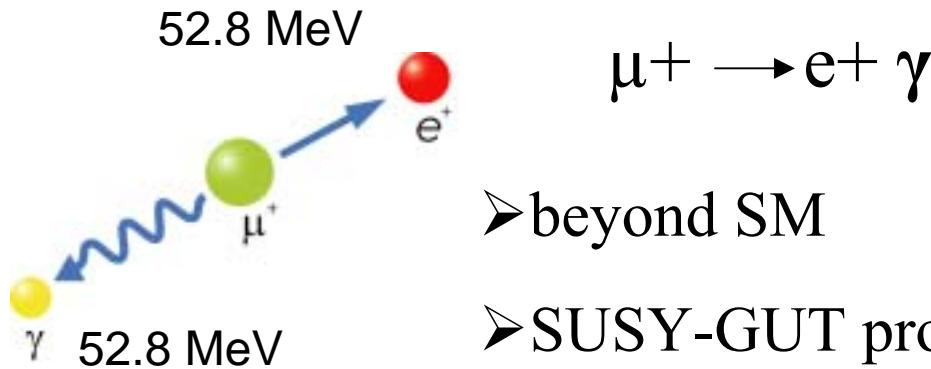
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Abstract

- About MEG Experiment
- PMT for MEG photon detector
- Works on Final Design of PMT
- PMT test at Univ. of Tokyo
- Summary

MEG Experiment



- beyond SM
- SUSY-GUT promising

MEGA(~1999)
Br 1.2×10^{-11}

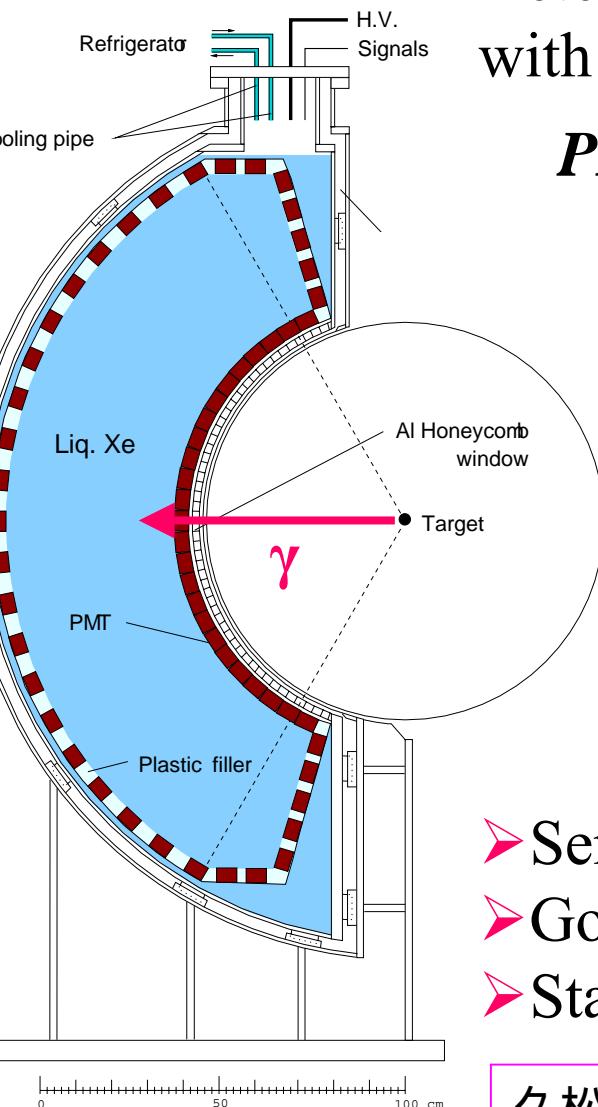
MEG
Br 10^{-14}

- Approved by Paul Scherrer Institut
- Using intense muon beam @PSI
 $1 \times 10^8/\text{sec}$
- Start of Physics Run : 2006



MEG Liq. Xe γ detector

Detect scintillation light with 800 Liter liq.Xe and with 830 PMTs

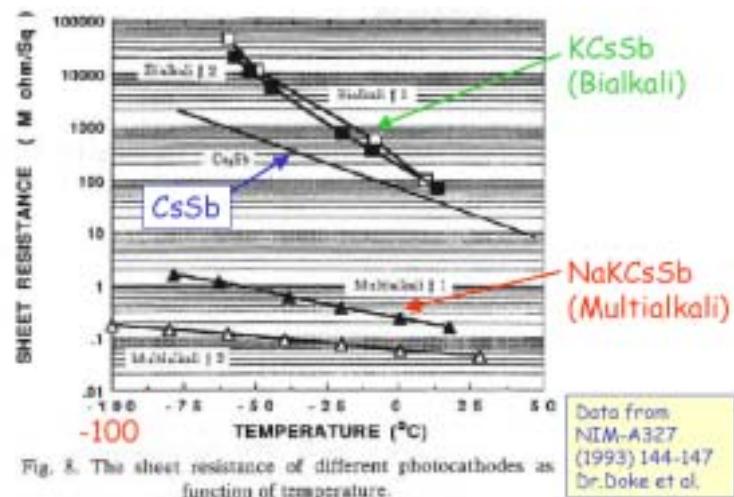


PMT for liq.Xe detector needs to be/have...

- Short
- Able to operate under magnetic field
 - Metal Channel Dynode
- Do not contaminate Xe
- Able to stand high pressure; up to 0.3MPa
 - Metal Cover → Positive HV
 - Parts on Bleeder Circuit
- Sensitive to VUV (Liq.Xe scintillation light)
- Good performance at 165K (Liq.Xe temperature)
- Stable under high rate background

PMT performance @165K

Temperature ↓
surface resistance of photocathode ↑
Quantum Efficiency ↓



First Ver.



Second Ver.

Photocathode	Rb-Cs-Sb	K-Cs-Sb
Material to reduce surface R	Mn layer	Al Strip
Q.E. @ 165K	~6%	?
Gain control	Difficult	Easy

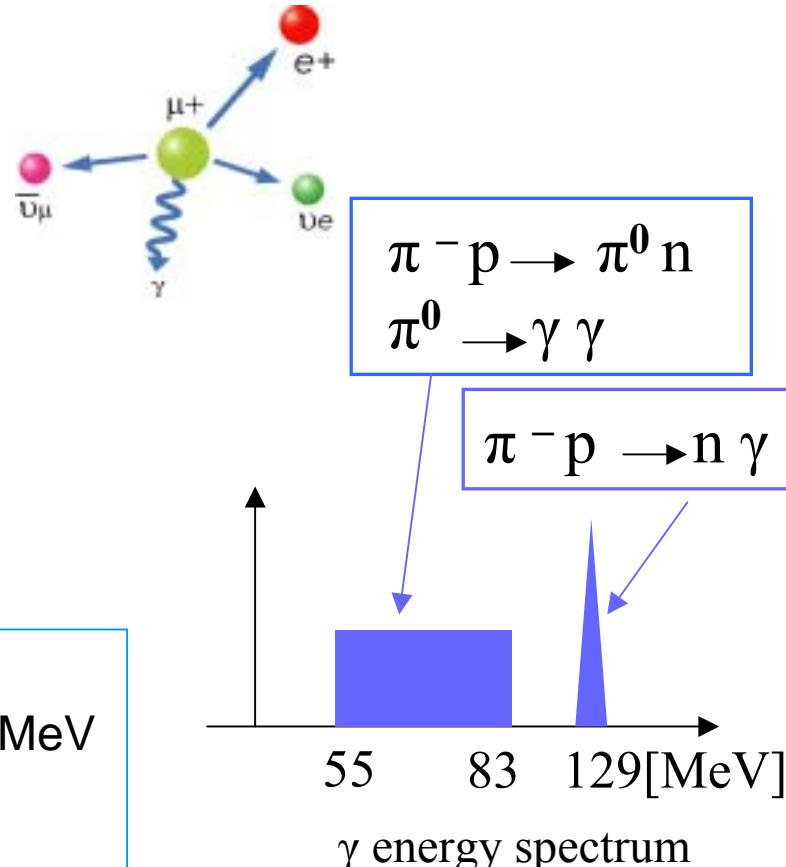
Major Background for PMT

- muon radiative decay
- Gamma from positron annihilation
- Neutrons from proton beam

T.Iwamoto, 27aSB-6

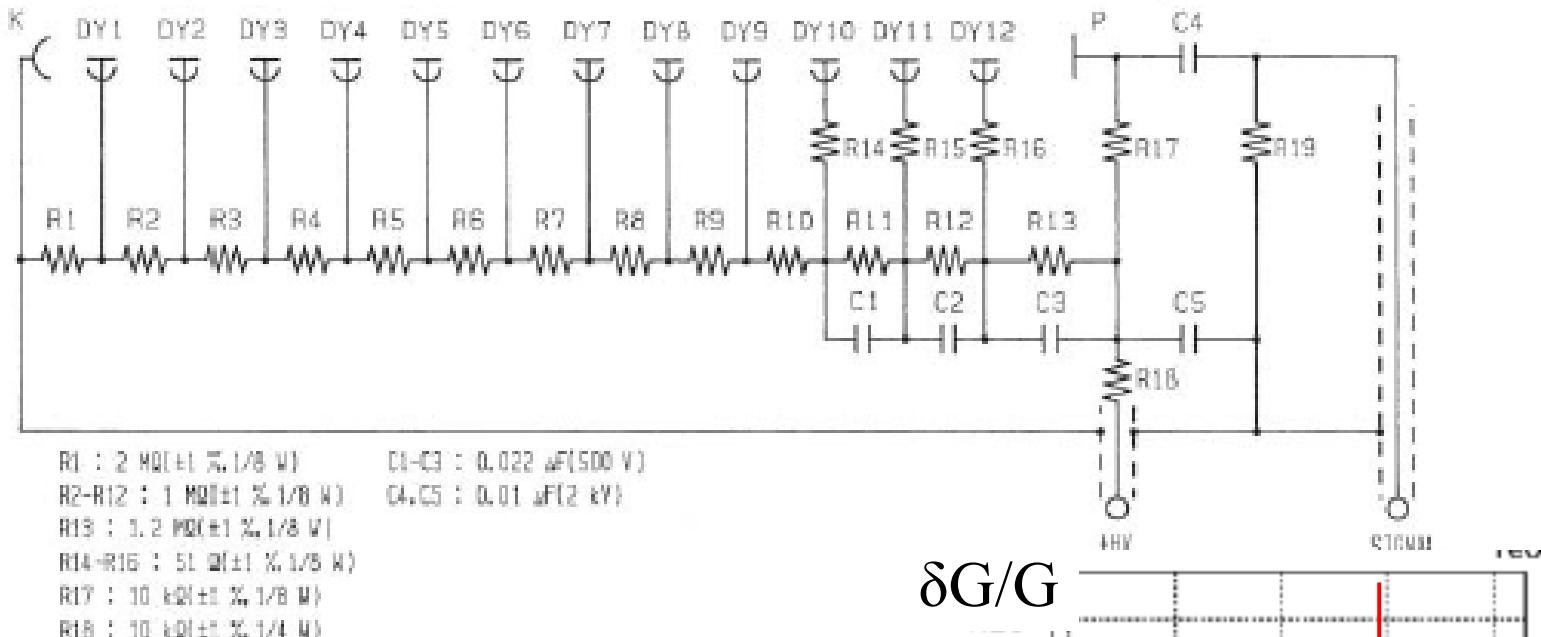
- neutrons from pion's CEX reaction
(@calibration run)

c.f. muegamma event



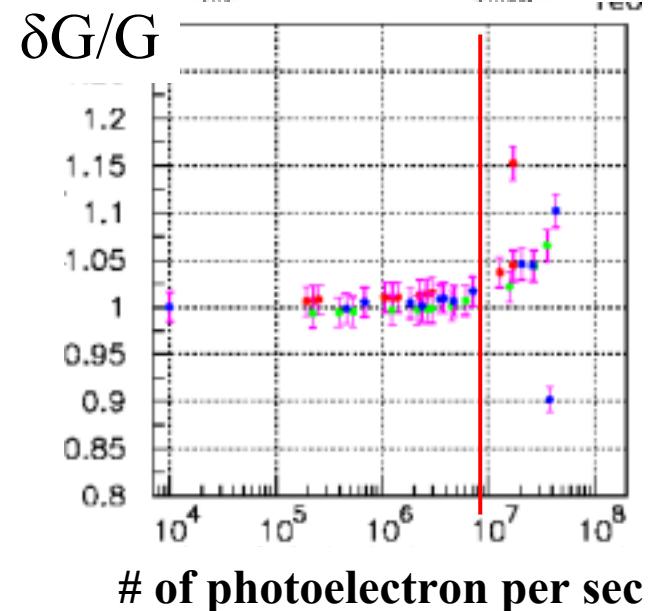
➡ BG level $\sim 2\mu\text{A}$ @ 10^6 gain ($\sim 10^7$ p.e./sec)

PMT performance under high rate B.G.



➤ Base Circuit for MEG PMT

Gain fluctuation due to
high rate background



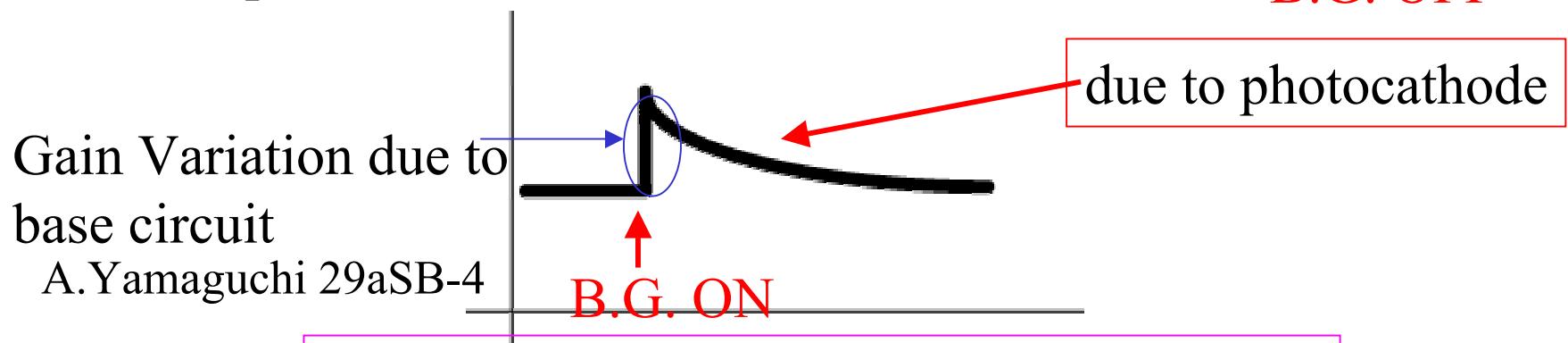
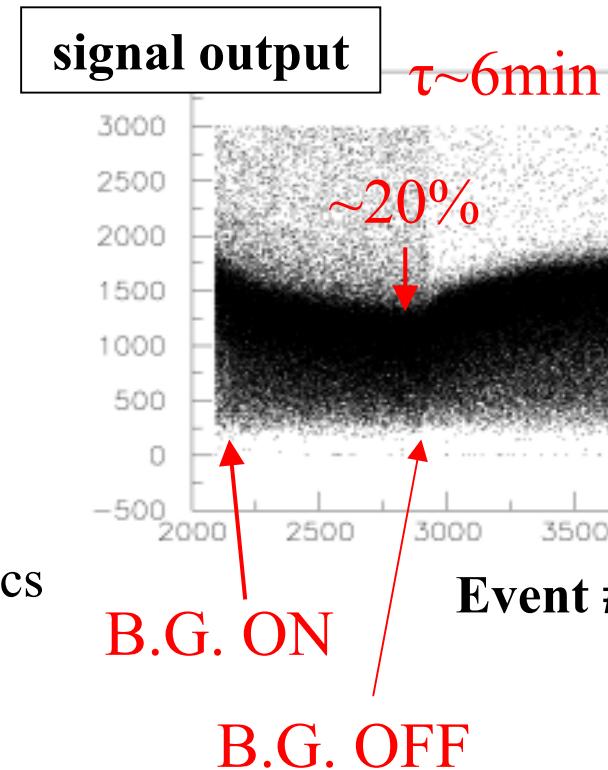
PMT performance under high rate B.G.

- Output from some First version PMTs deteriorates under high rate background.

Related to the characteristics of photocathode in the low temperature

- Rb-Cs-Sb + Mn Layer @ First version PMT
- To obtain “higher” gain, added more alkali
- Larger fraction of alkali changed the characteristics of photocathode

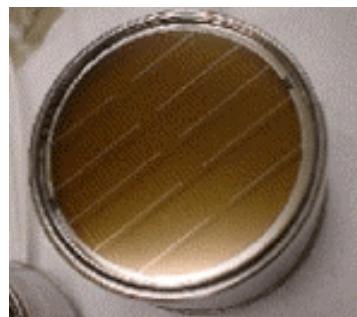
PMT outputs deterioration from two reasons:



PMT for MEG



First Ver.



Second Ver.



Final Ver.

Photocathode	Rb-Cs-Sb	K-Cs-Sb	K-Cs-Sb
Material to reduce surface R	Mn layer	Al Strip	Al Strip (doubled)
Gain control	Difficult	Easy	Easy
Q.E. @ 165K	~6%	?	??

PMT Test @ Univ. of Tokyo

- How much has Q.E. improved?
- Will PMT survive the high background environment?
 - low temperature effect on photocathode
 - bleeder circuit current

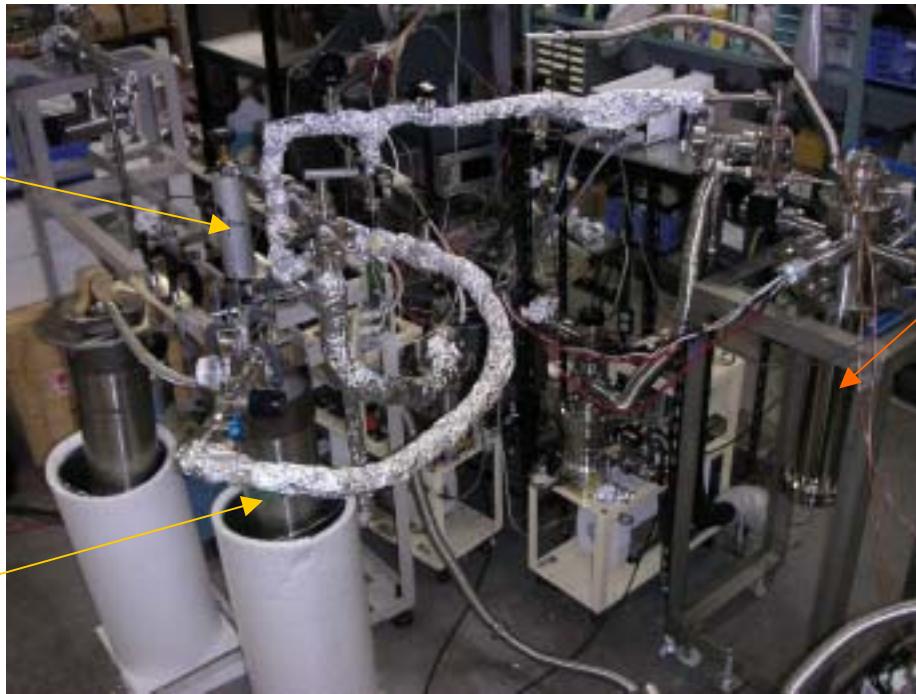
A. Yamaguchi

PMT Test facility @Univ. of Tokyo

Purification system

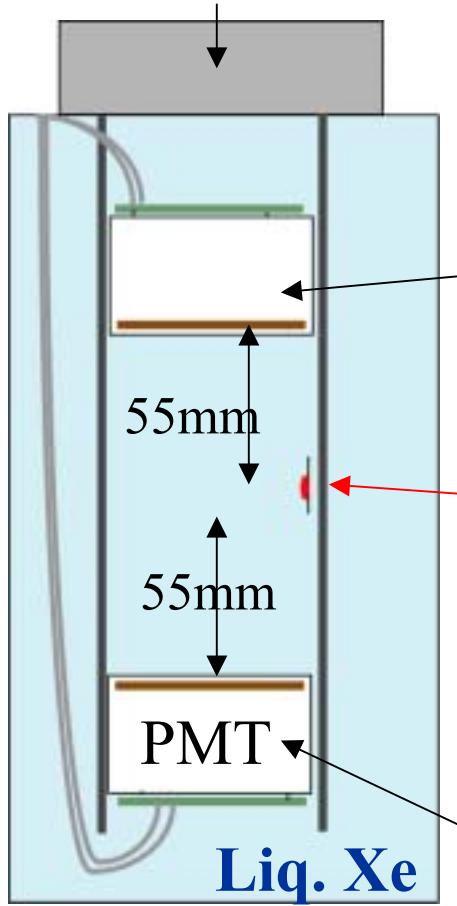
Liq.Xe chamber

Xe tank



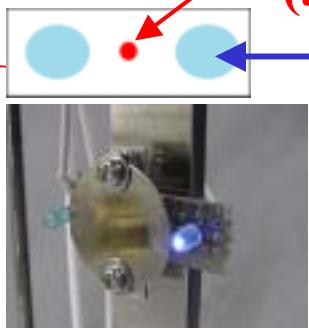
PMT Test Set up *Q.E. measurement*

Pulse tube refrigerator



Reference PMT

^{241}Am
(alpha source)



Observe 5.5MeV alpha event
Gain calibration using LED

$$g = \frac{c}{eM}^2$$

$$^2 = g \frac{e}{c} (M - M_0) + ^2_0$$

g: gain

c: ADC least count

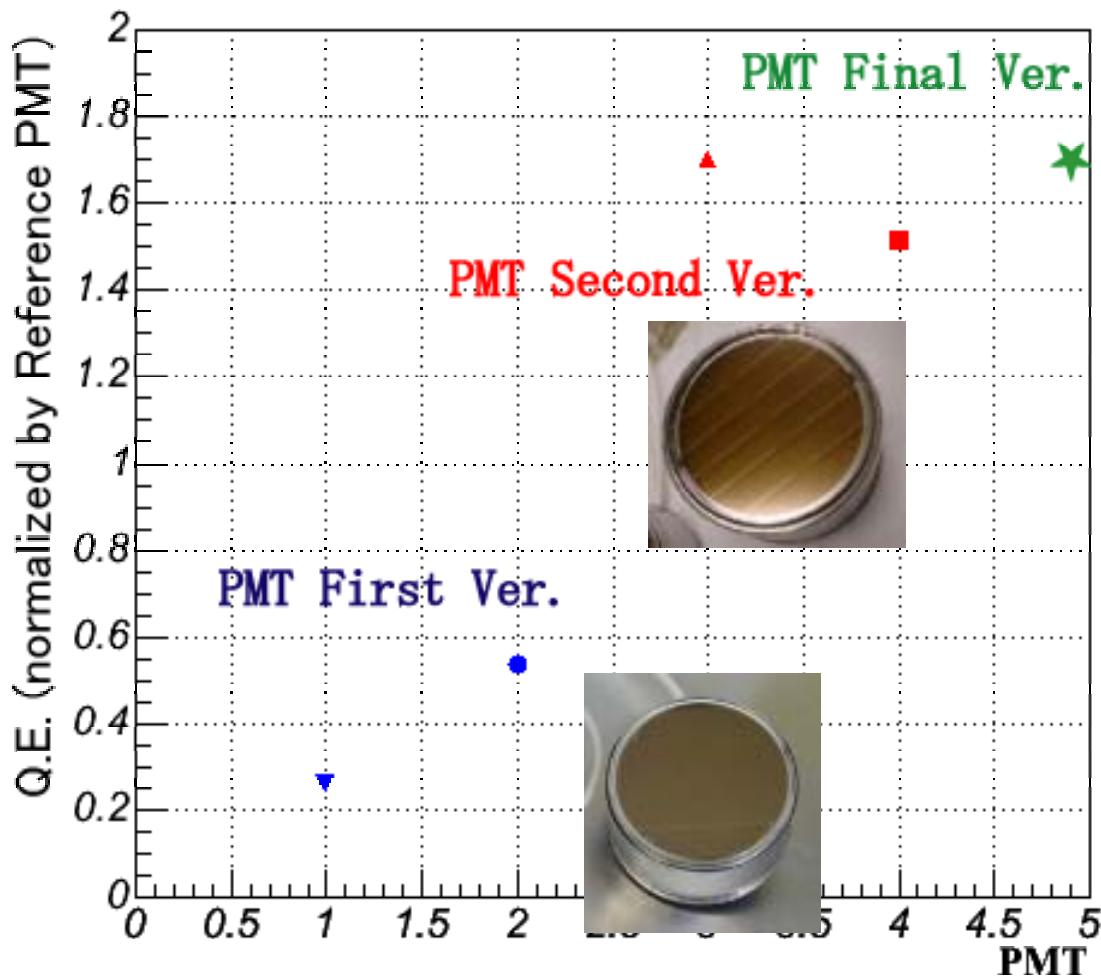
: standard deviation

M: mean of ADC spectrum

e: elementary electric charge

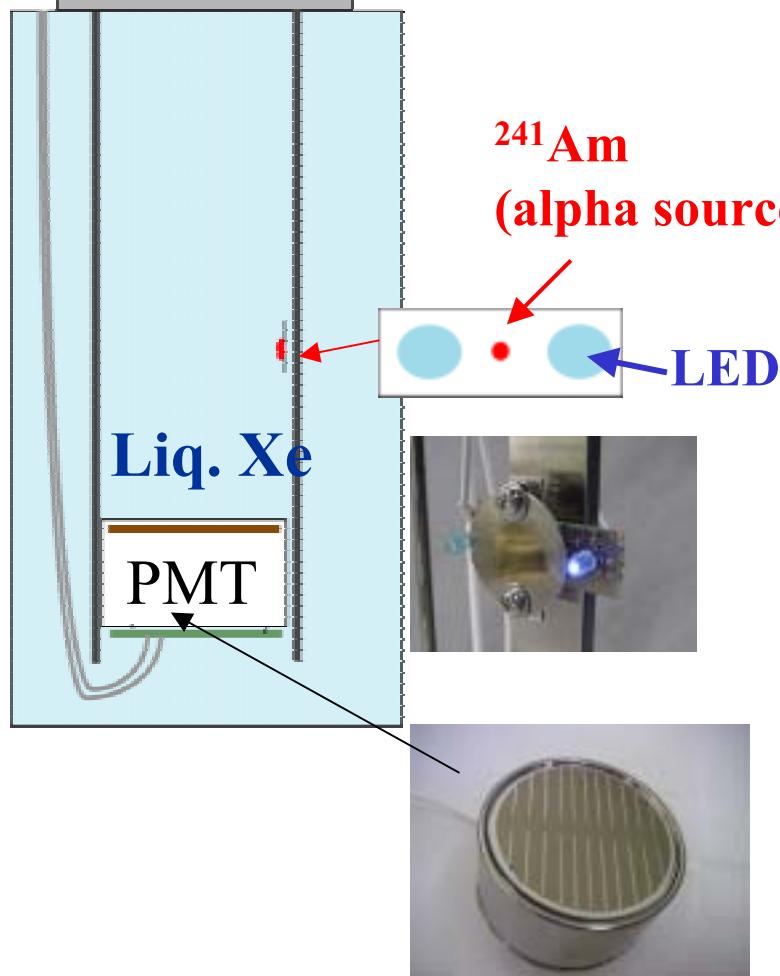
Gain : 10^6

Q.E. measurement



PMT Test Set up *Rate dependence test*

Pulse tube refrigerator



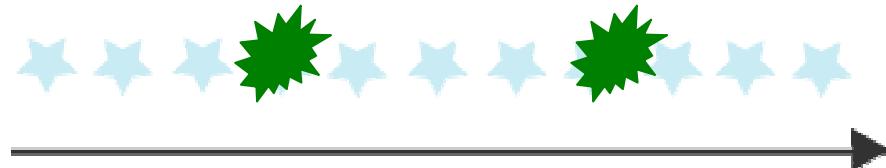
LED

- simulate the high rate background
- pulse height: 4000~7200 p.e./event
- pulse shape: ~10nsec
- rate: 500Hz ~ 10KHz

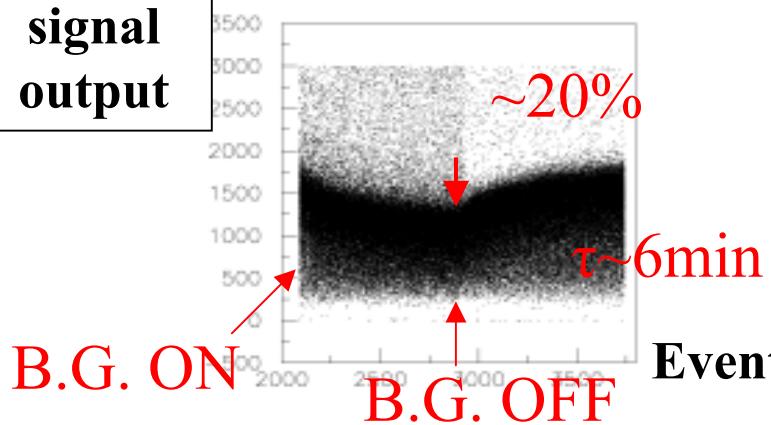
Background Level Upper limit :
 $2\mu\text{A}$, $1*10^7$ p.e./sec

alpha

Observe 5.5MeV alpha event,
~200Hz



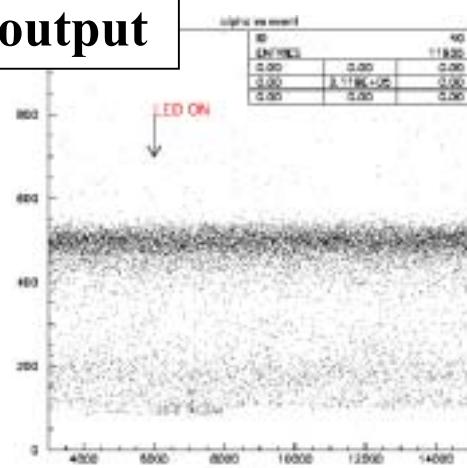
signal
output



Background Level Upper limit :
 $2\mu\text{A}$, $1*10^7$ p.e./sec

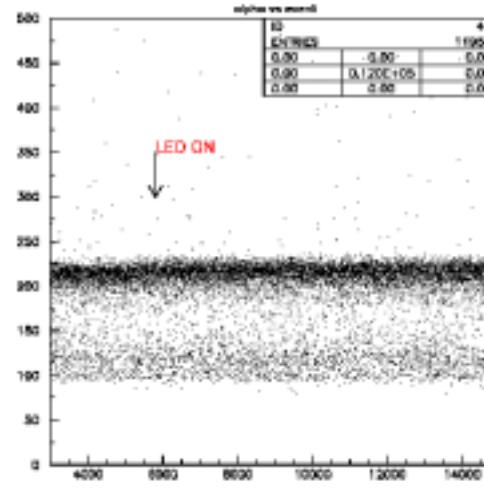
c.f. First Version PMT

signal output



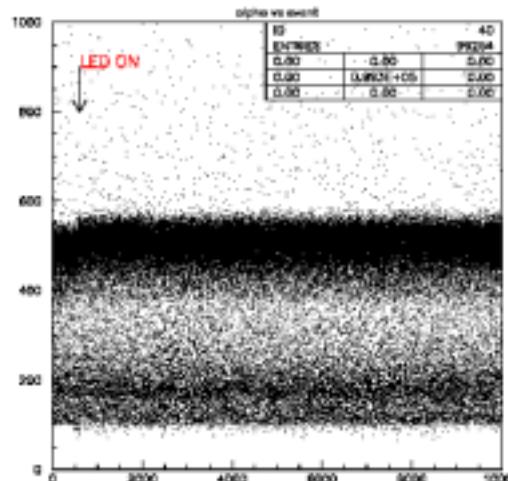
Background: $0.34\mu\text{A}$

$2.0*10^6$ p.e./sec



$1.2\mu\text{A}$

$7.2*10^6$ p.e./sec



$2.2\mu\text{A}$

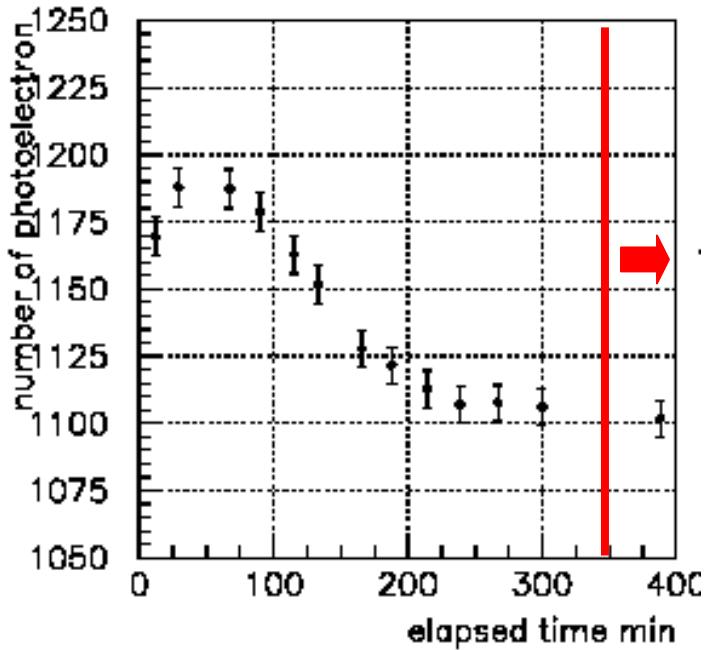
$1.3*10^7$ p.e./sec

Summary

- Works on Final Design of PMT have finished,
Adopting new photocathode material: K-Cs-Sb
Adding Al Strip Pattern : reduction of surface resistance
- Final Version of PMT is tested @ liq.Xe.
- New photocathode mentioned above works quite well;
- Q.E. is expected to be ~4 times bigger than that of R6041Q.
- Stable output under the estimated background level in MEG

PMT stability, DAQ Procedure

DAQ started after all chamber
components become low temperature



Trigger : alpha self trigger
DAQ Procedure :

Pedestal Run

- Gain Calibration
- alpha run

Condition and Procedure

- Gain $1*10^6$
- Trigger: alpha self trigger (veto by LED driver pulse)
- Procedure

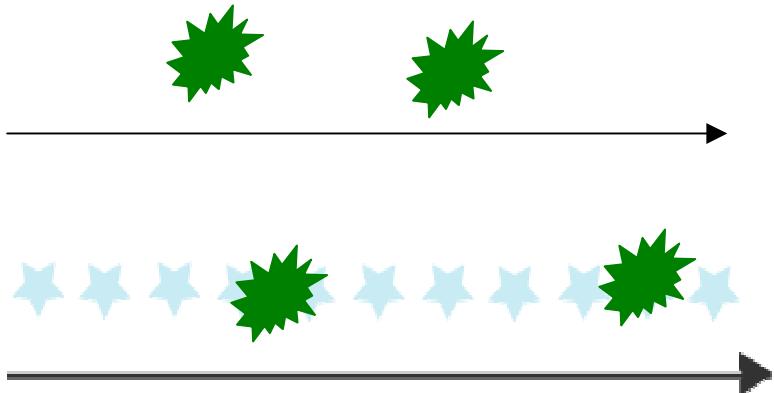
Pedestal Run & Gain calibration using LED

Alpha Run @ LED OFF 20 min



Alpha Run @ LED ON 20 min

-Change LED Pulse height, rate



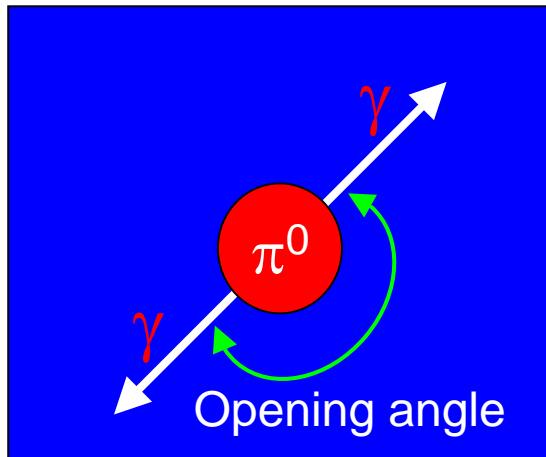
π^0 Beam Test at PSI

π^- (at rest) + p $\rightarrow \pi^0 + n$,

$\pi^0(28\text{MeV}/c) \rightarrow \gamma + \gamma$

($54.9\text{MeV} < E_\gamma < 82.9\text{MeV}$)

Almost monochromatic γ



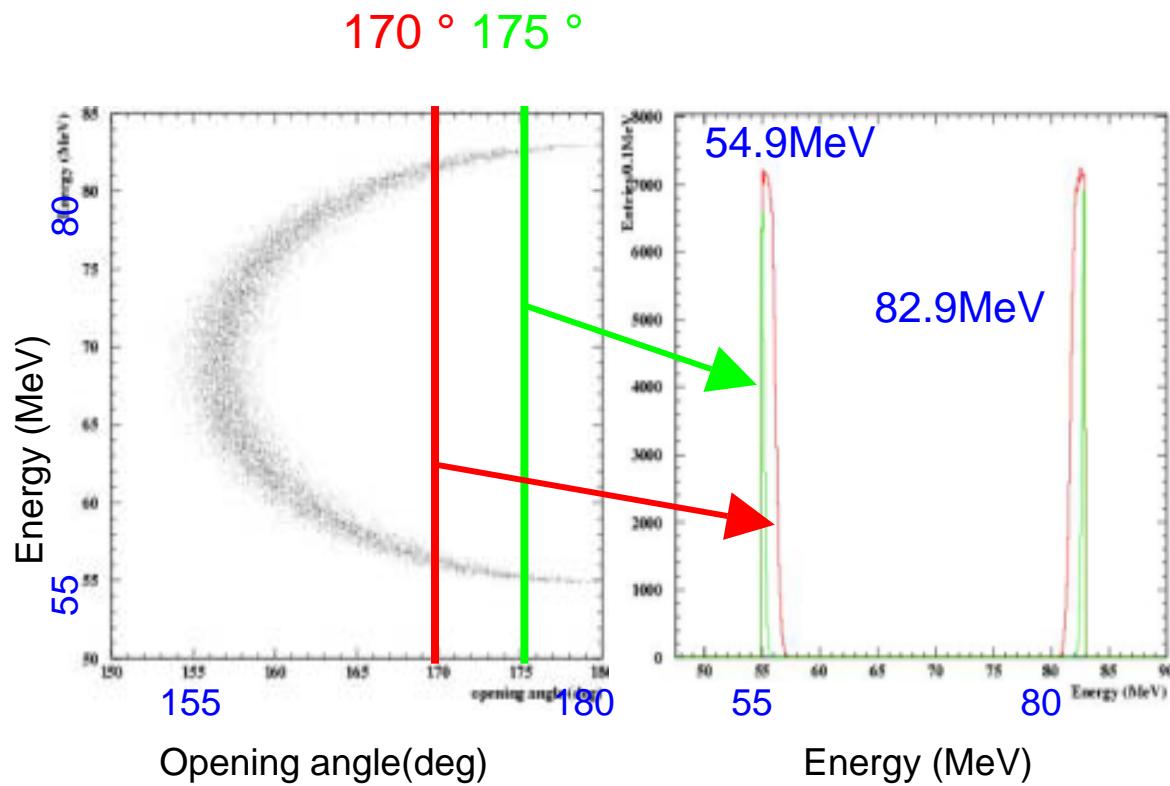
$\pi^- + p \rightarrow n(8.9\text{MeV})$

+ γ (129MeV)

linearity check

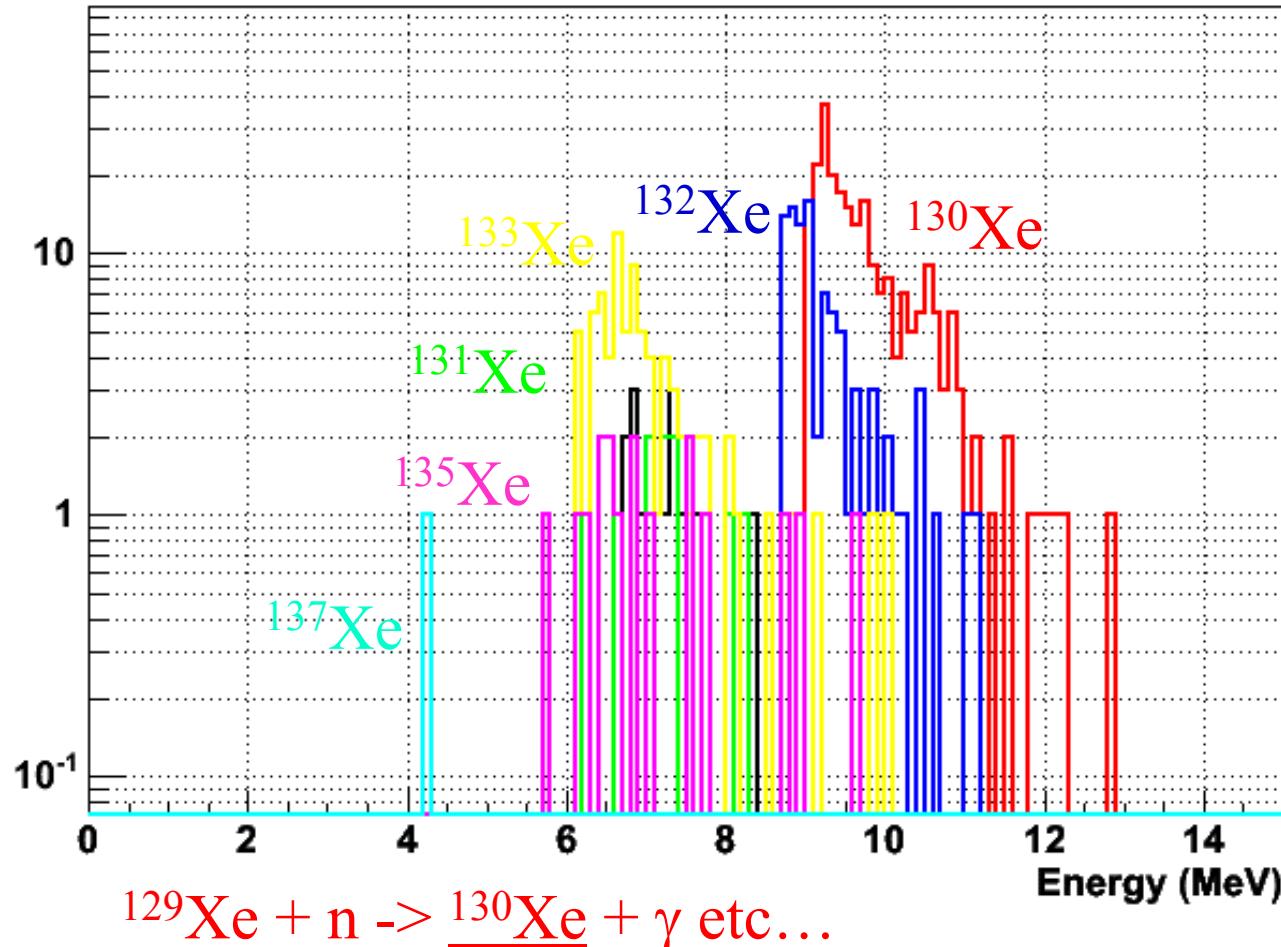
55, 83 and 129MeV

neutron response



Radiative Capture events in Xe

Capture Events in Xe

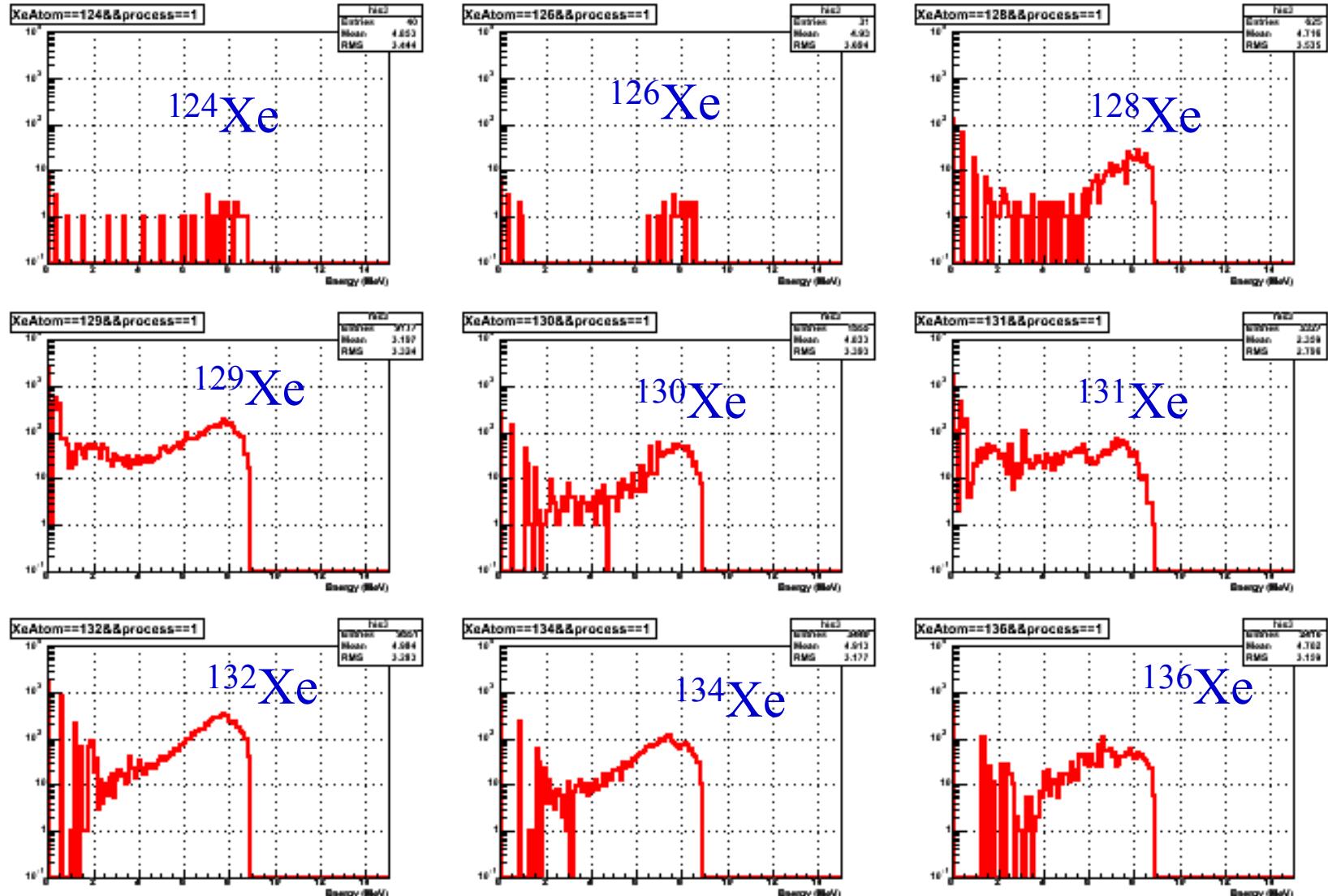


Many γ 's are emitted, not one.

γ from radiative muon decay

- $10^8 \mu/\text{s} \rightarrow 10^6 \mu\text{eV}\nu\nu/\text{s}$
- acceptance 10%
- Mean deposit energy 5MeV
- 1 photon = 24eV
- Xe detector front face 200PMTs, QE 10%, coverage 50%, photon collection 50%
- $10^6 \mu\gamma \times 0.1 \times 5 \times 10^6 \text{ MeV} \times 0.1 \times 10^6 \times 1.6 \times 10^{-19} \text{ C} \times 0.5 \times 0.5 / 24 \text{ eV} / 200 \text{ PMTs}$
= 0.4 μA

Inelastic reaction of different nuclei in Xe



0MeV

15MeV

There are edges for different Xe nuclei around 9MeV.

CRYOGENIC OPERATION FOR LARGE-PROTO DETECTOR

-Heat Load-

Phase	LXe (L)	PMT	Heat Load W@165K			Total (W)
			Static	PMT	Cable	
L_PROTO	120	250	24	16	10	50
Final	800	800	20	52	50	122

- *Static heat load depends on manufacturers design
- *PMT power dissipation 65mW/PMT
- *Due to number and length of cables

PMT gain calibration 1

How to gain calibration?

PMTに入射した光子が光電面で光電子をたたき出す過程をPoisson分布であるとすると

$$\sigma_{Npe} = \sqrt{Npe} \quad (Npe : \text{光電子数})$$

増幅率GのPMTと1ch当たりの電荷量CのADCで見ると

$$G = \frac{C \times M}{e \times Npe} \quad (e : \text{電気素量}, M : \text{ADCスペクトルの平均値})$$

$$\therefore Npe = \frac{C \times M}{e \times G}$$

また、

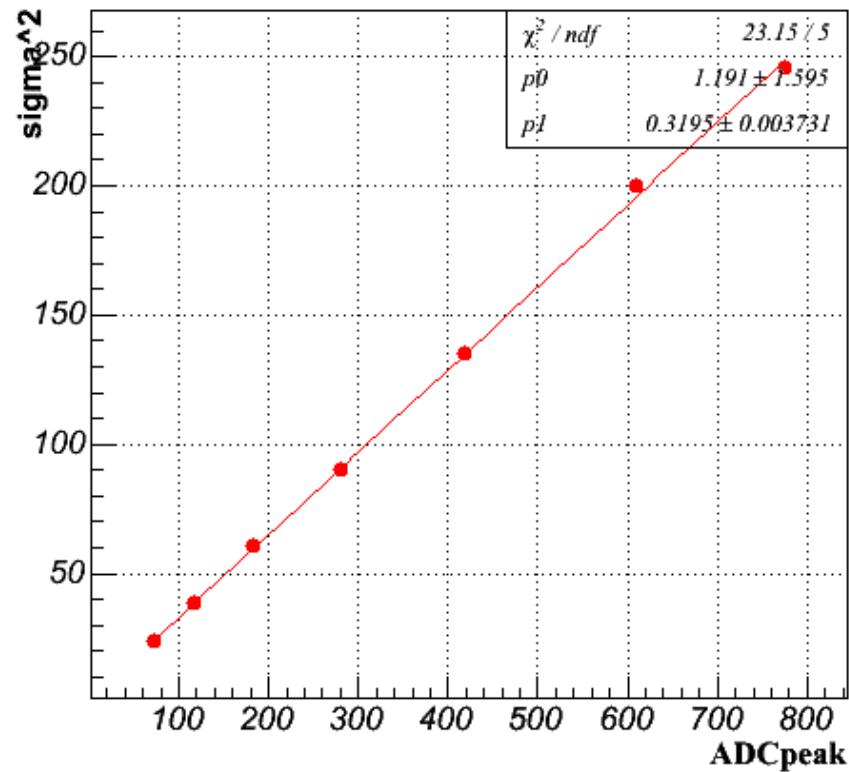
$$\sigma_{Npe} = \frac{C \times \sigma_{ADC}}{e \times G}$$

以上より

$$\sigma_{ADC}^2 = \frac{C \times M}{e \times G} = \left(\frac{C \times \sigma_{ADC}}{e \times G} \right)^2$$

$$\therefore \sigma_{ADC}^2 = \frac{e \times G}{C} \times M$$

M v.s sigma^2のplotの傾きからgainを算出



gain calibration(sample)